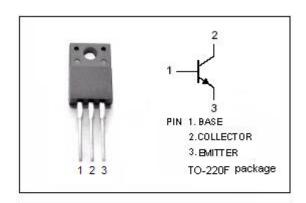


isc Silicon NPN Power Transistor

DESCRIPTION

- High Collector-Emitter Breakdown Voltage V_{CEO}= 160V(Min)
- Complement to Type 2SA1659
- Full-mold package that does not require an insulating board or bushing when mounting.
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

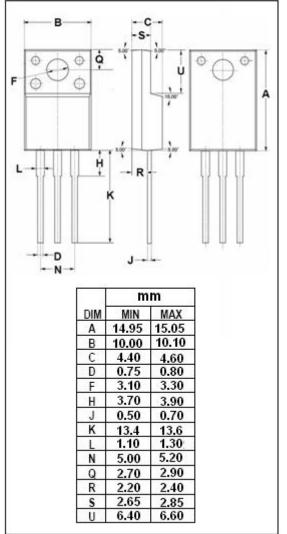


APPLICATIONS

Designed for high voltage applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|--------------------|---|-------|--------------|--|
| V _{CBO} | Collector-Base Voltage | 160 | V | |
| V _{CEO} | Collector-Emitter Voltage | 160 | V | |
| V _{EBO} | Emitter-Base Voltage 5.0 | | V | |
| I _{C(DC)} | Collector Current(DC) | 1.5 | А | |
| I _{B(DC)} | Base Current | 0.15 | А | |
| Pc | Collector Power Dissipation @T _C =25℃ | 20 | W | |
| TJ | Junction Temperature | 150 | $^{\circ}$ C | |
| T _{stg} | T _{stg} Storage Temperature | | °C | |





isc Silicon NPN Power Transistor

2SC4370

ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

| ., 20 o amore operation | | | | | | | |
|-------------------------|--------------------------------------|--|-----|------|-----|------------|--|
| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT | |
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | I _C = 10mA ; I _B = 0 | 160 | | | V | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C = 500mA; I _B = 50mA | | | 1.5 | V | |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = 500mA ; V _{CE} = 5V | | | 1.0 | V | |
| Ісво | Collector Cutoff Current | V _{CB} = 160V ; I _E = 0 | | | 1.0 | μ А | |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 5V; I _C =0 | | | 1.0 | μА | |
| h _{FE} | DC Current Gain | I _C = 100mA ; V _{CE} = 5V | 70 | | 240 | | |
| Сов | Output Capacitance | I _E = 0 ; V _{CB} = 10V;f= 1.0MHz | | 25 | | pF | |
| f _T | Current-Gain—Bandwidth Product | I _C = 100m A ; V _{CE} = 10V | | 100 | | MHz | |

♦ h_{FE} Classifications

| 0 | Y |
|--------|---------|
| 70-140 | 120-240 |

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